

# STPS2045CH

## Datasheet

## 45 V power Schottky rectifier



IPAK

### **Features**

- Very small conduction losses
- Avalanche specification
- Low forward voltage drop
- High frequency operation
- ECOPACK<sup>®</sup>2 compliant

### **Applications**

- DC/DC converter
- Battery charger
- SMPS
- Desktop power
- Auxiliary power

### **Description**

This dual-diode common cathode Schottky rectifier is ideal for high frequency switch mode power supply.

Packaged in IPAK, the STPS2045CH is optimized for notebook, game station and desktop adapters, providing in these applications a good efficiency at both low and high load.

STPS2045CH	
Products	summary
I <sub>F(AV)</sub>	2 x 10 A

V<sub>RRM</sub>

V<sub>F</sub> (typ.)

T<sub>j</sub> (max.)

Product status link

45 V

0.50 V

175 °C

## 1 Characteristics

### Table 1. Absolute ratings (limiting values, at 25 °C unless otherwise specified)

Symbol	Parameter			Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse voltage			45	V	
I <sub>F(RMS)</sub>	Forward rms current		20	Α		
I <sub>F(AV)</sub>		T <sub>C</sub> = 155 °C	Per diode	10	_	
	Average forward current $0 = 0.5$ , square wave $T_C = 150^{\circ}$		Per device	20	A	
I <sub>FSM</sub>	Surge non repetitive forward current $t_p$ = 10 ms sine-wave			150	А	
P <sub>ARM</sub>	Repetitive peak avalanche power $t_p = 10 \ \mu s, T_j = 125 \ ^{\circ}C$			280	W	
T <sub>stg</sub>	Storage temperature range			-65 to +175	°C	
Тј	Maximum operating junction temperature (1)			+175	°C	

1.  $(dP_{tot'}/dT_j) < (1/R_{th(j-a)})$  condition to avoid thermal runaway for a diode on its own heatsink.

### Table 2. Thermal resistance parameters

Symbol	Parameter	Value	Unit	
R <sub>th(j-c)</sub> Ju	Junction to case	Per diode	2.5	°C/W
		Total	1.6	
R <sub>th(c)</sub>	Coupling		0.7	

For more information, please refer to the following application note :

AN5088 : Rectifiers thermal management, handling and mounting recommendations

#### Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25 °C	V <sub>R</sub> = V <sub>RRM</sub>	-		100	μA
		T <sub>j</sub> = 125 °C		-	7	15	mA
	Forward voltage drop	T <sub>j</sub> = 125 °C	I <sub>F</sub> = 10 A	-	0.50	0.57	
V <sub>F</sub> <sup>(2)</sup>		T <sub>j</sub> = 25 °C	I= = 20 A	-		0.84	V
		T <sub>j</sub> = 125 °C	1F - 20 A	-	0.65	0.72	

1. Pulse test:  $t_p = 5 \text{ ms}, \delta < 2\%$ 

2. Pulse test:  $t_p = 380 \ \mu s, \ \delta < 2\%$ 

To evaluate the conduction losses, use the following equation:

 $P = 0.42 \text{ x } I_{F(AV)} + 0.015 \text{ x } I_{F}^{2} (RMS)$ 

For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode



## 1.1 Characteristics (curves)













# 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: www.st.com. ECOPACK<sup>®</sup> is an ST trademark.

## 2.1 IPAK package information

- Cooling method: by conduction (C)
- Epoxy meets UL 94,V0

#### Figure 8. IPAK package outline



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	Dimensions					
Ref.	Millim	Millimeters		hes		
	Min.	Max.	Min.	Max.		
А	2.20	2.40	0.087	0.094		
A1	0.90	1.10	0.035	0.043		
b	0.64	0.90	0.025	0.035		
b2		0.95		0.037		
b4	5.20	5.43	0.205	0.214		
B5	0.30	typ.	0.012	2 typ.		
С	0.45	0.60	0.018	0.024		
c2	0.46	0.60	0.018	0.024		
D	6.00	6.20	0.236	0.244		
E	6.40	6.65	0.252	0.261		
e	2.28	typ.	typ.0	.090		
e1	4.40	4.60	0.173	0.181		
Н	16.10	) typ.	0.634	4 typ.		
L	9.0	9.60	0.354	0.378		
L1	0.80	1.20	0.031	0.047		
L2	0.80 typ.	1.25	0.031 typ.	0.049		
V1	+10°		+10			

### Table 4. IPAK package mechanical data



# **3** Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS2045CH	S20 45CH	IPAK	0.31 g	75	Tube

Table 5. Ordering information

## **Revision history**

	Date	Version	Changes
	21-Jun-2012	1	First issue.
	09-Oct-2014	2	Updated Table 2 and IPAK package informations.
	27-Nov-2018	3	Removed figure 1 and figure 9. Updated Table 1. Absolute ratings (limiting values, at 25 °C unless otherwise specified), Figure 5. Reverse leakage current versus reverse voltage applied (typical values, per diode), Figure 7. Forward voltage drop versus forward current (per diode) and Table 5. Ordering information.

#### Table 6. Document revision history



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